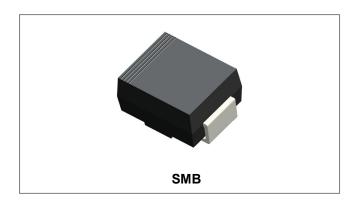


# MURS360B

Technical Data Data Sheet N1491, Rev. A RoHS 🗭

# **MURS360B ULTRAFAST RECTIFIER**



## Features

- Glass Passivated Die Construction
- Ideally Suited for Automatic Assembly
- Low Forward Voltage Drop, High Efficiency
- Low Power Loss
- Super Fast Recovery Time
- Plastic Case Material has UL Flammability Classification Rating 94V-O
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

### **Applications**

- Switching Power Supply
- Power Switching Circuits
  - General Purpose

### Maximum Ratings and Electrical Characteristics @T<sub>A</sub>=25°C unless otherwise specified

Characteristic	Symbol	MURS360B	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	600	V
RMS Reverse Voltage	Vr(RMS)	420	V
Average Rectified Output Current (Note 1) $@T_A = 55^{\circ}C$	lo	3.0	A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>	150	A
Forward Voltage (per element) @I <sub>F</sub> = 3.0A	V <sub>FM</sub>	1.25	V
Peak Reverse Current $@T_A = 25^{\circ}C$ At Rated DC Blocking Voltage $@T_A = 125^{\circ}C$	I <sub>RM</sub>	10 500	μΑ
Maximum Reverse Recovery Time (Note 1)	Trr	50	ns
Typical Thermal Resistance Junction to Ambient (Note 2)	R <sub>0JA</sub>	25	K/W
Junction Temperature	TJ	-55 to +150	°C
Storage Temperature Range	Тѕтд	-55 to +150	°C

Note: 1. Reverse Recovery Test Conditions: IF=0.5A, IR=1.0A, IRR=0.25A

2. Mount on Cu-Pad Size 16mm×16mm on P.C.B.

- China Germany Korea Singapore United States
  - http://www.smc-diodes.com sales@ smc-diodes.com -

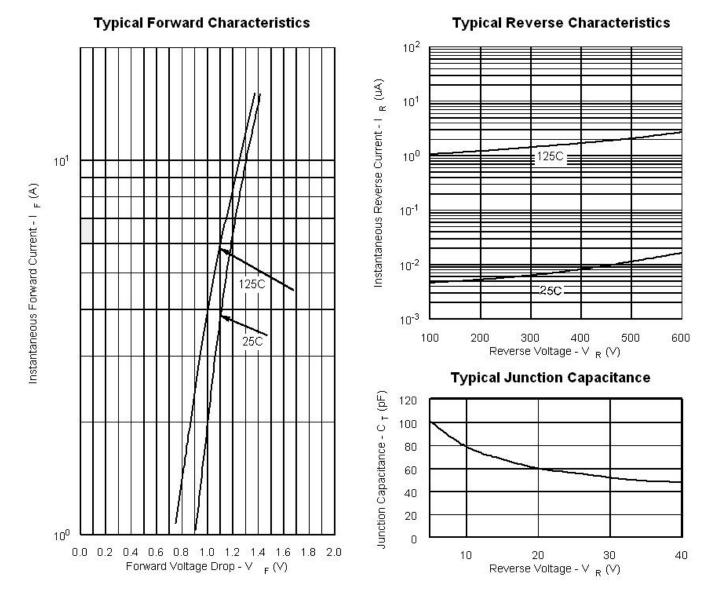
### **Circuit Diagram**





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### **Ratings and Characteristics Curves**



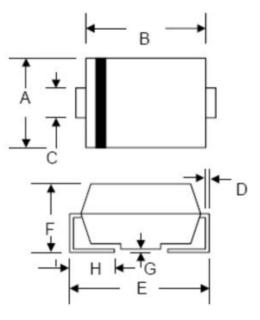
MURS360B

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### **Mechanical Dimensions SMB**



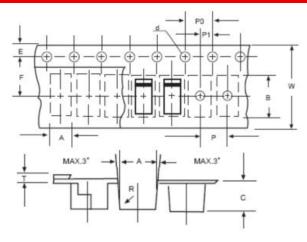
SYMBOL	Millimeters		Inches	
SYMBOL -	Min.	Max.	Min.	Max.
Α	3.30	3.94	0.130	0.155
В	4.06	4.70	0.160	0.185
С	1.80	2.20	0.071	0.087
D	0.152	0.305	0.006	0.012
E	4.80	5.59	0.189	0.220
F	2.10	2.60	0.083	0.102
G	0.051	0.203	0.002	0.008
н	0.76	1.52	0.030	0.060

## **Ordering Information**

Device	Package	Shipping
MURS360B	SMB (Pb-Free)	3000pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

### **Carrier Tape Specification SMB**



SYMBOL	Millimeters		
STMBOL	Min.	Max.	
Α	2.97	3.17	
В	5.70	5.90	
С	2.32	2.52	
d	1.40	1.60	
E	1.40	1.60	
F	5.60	5.70	
Р	3.90	4.10	
P0	3.90	4.10	
P1	1.90	2.10	
Т	0.25	0.35	
W	11.80	12.20	

• China - Germany - Korea - Singapore - United States •

# **Marking Diagram**

3

6

В

Т

ΥY

ww

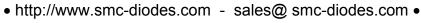
MURS360B XXXXX

- Where XXXXX is YYWWL MURS
  - = Device Type = Forward Current (3A)
  - = Reverse Voltage (60V)
  - = Package type
  - = Year
  - = Week = Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

MURS360B







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